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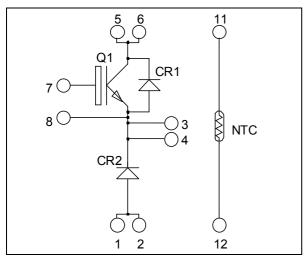


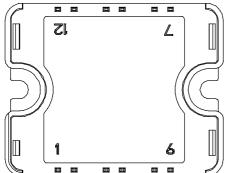






Buck chopper Trench + Field Stop IGBT3 Power Module





Pins 1/2; 3/4; 5/6 must be shorted together

$V_{CES} = 600V$ $I_{C} = 75A$ @ $T_{C} = 80^{\circ}C$

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	100	
1 _C	I _C Continuous Collector Current	$T_C = 80$ °C	75	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	140	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	250	W
RBSOA	Reverse Bias Safe Operating Area	$T_{\rm J} = 150^{\circ}{\rm C}$	150A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		1.5	1.9	V
$V_{CE(sat)}$		$I_{\rm C} = 75 {\rm A}$ $T_{\rm j} = 150 {\rm ^{\circ}C}$		1.7		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 600 \mu A$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		4620		
Coes	Output Capacitance	$V_{CE} = 25V$		300		pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz		140		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		110		ns
T_{r}	Rise Time	$V_{GE} = \pm 15V$		45		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 75A$		200		
$T_{\rm f}$	Fall Time	$R_G = 4.7\Omega$		40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$		120		
T_{r}	Rise Time	$V_{\text{Bus}} = 300V$		50		ns
$T_{d(off)}$	Turn-off Delay Time	$I_C = 75A$		250		
$T_{\rm f}$	Fall Time	$R_G = 4.7\Omega$		60		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		0.35		mJ
Lon	Turn-on Switching Energy	$V_{Bus} = 300V$ $T_j = 150^{\circ}C$		0.6		1113
E _{off}	Turn-off Switching Energy	$I_C = 75A$ $T_j = 25^{\circ}C$		2.2		mJ
Loff	Turn-on Switching Energy	$R_G = 4.7\Omega$ $T_j = 150^{\circ}C$		2.6		1113

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	$V_R=600V$	$T_j = 25$ °C			250	μΑ
	-		$T_{j} = 150^{\circ}C$			500	
I_{F}	DC Forward current		$Tc = 80^{\circ}C$		75		Α
V_{-}	V_F Diode Forward Voltage $ I_F = 75A $ $V_{GE} = 0V $		$T_i = 25$ °C		1.6	2	
V F		$V_{GE} = 0V$	$T_i = 150^{\circ}C$		1.5		V
t_{rr}	Reverse Recovery Time	Y 75.4	$T_j = 25^{\circ}C$		100		ns
·rr	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		150		113
Qrr	Reverse Recovery Charge	$ \begin{aligned} I_F &= 75A \\ V_R &= 300V \\ di/dt &= 2000A/\mu s \end{aligned} $	$T_j = 25^{\circ}C$		3.6		μC
Q _{rr}	Reverse Recovery Charge		$T_j = 150$ °C		7.6		μС
Е	Davience Dagavient Energy		$T_i = 25^{\circ}C$		0.85		mJ
E_{r}	Reverse Recovery Energy		$T_j = 150$ °C		1.8		1113

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Thermal and package characteristics

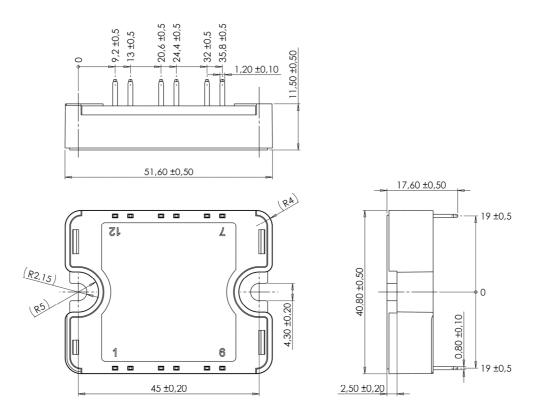
Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	lunction to Case Thermal Resistance		IGBT			0.60	°C/W
			Diode			0.98	C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range Storage Temperature Range			-40		175	
T_{STG}				-40		125	$^{\circ}\mathrm{C}$
$T_{\rm C}$	Operating Case Temperature -40 100						
Torque	Mounting torque	To heatsink	M4	2	•	3	N.m
Wt	Package Weight				•	80	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B _{25/85}	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature } \\ R_{T}: \text{ Thermistor value at T}$$

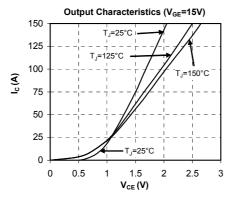
SP1 Package outline (dimensions in mm)

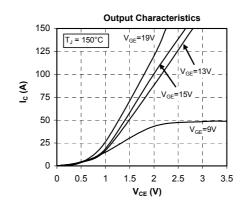


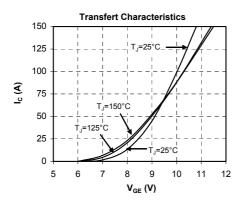
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

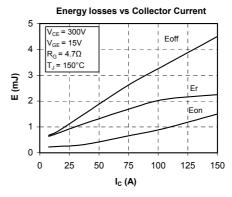


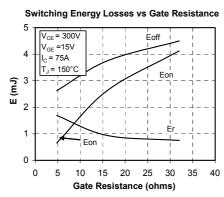
Typical Performance Curve

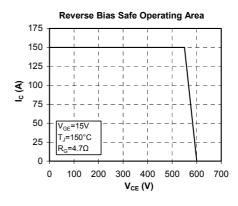


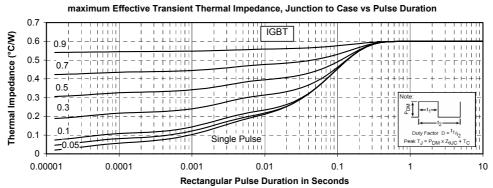




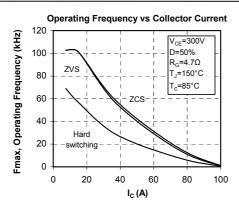


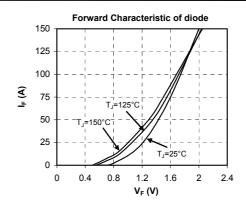


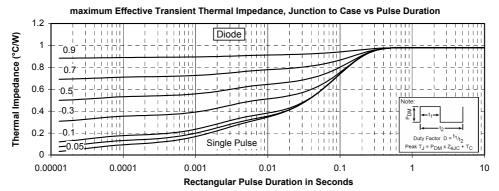












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